

SD12C

DESCRIPTION

The SD12C Series is designed for applications requiring transient overvoltage protection capability. They are intended for use in voltage and ESD sensitive equipment such as computers, printers, business machines, communication systems, medical equipment and other applications. These devices are ideal for situations where board space is at a premium.

This series has been specifically designed to protect sensitive components which are connected to power, data and transmission lines from overvoltage caused by ESD(electrostatic discharge), CDE (Cable Discharge Events), and EFT (electrical fast transients).

ORDERING INFORMATION

- ♦ Device: SD12C
- ♦ Package: SOD-323
- ♦ Material: Halogen free
- ♦ Packing: Tape & Reel
- ♦Quantity per reel: 3,000pcs

Bidirectional TVS Diodes

FEATURES

- \diamond 350 Watts Peak Pulse Power per (tp=8/20µs)
- ♦ Protects one I/O line (bidirectional)
- ♦ Low clamping voltage
- ♦ Working voltages :3V,5V,8V,12V,15V,18V,24V, 36V
- ♦Low leakage current

MACHANICAL DATA

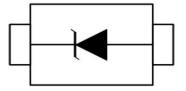
- ♦ SOD-323 package
- ♦ Flammability Rating: UL 94V-0
- ♦ Packaging: Tape and Reel
- ♦ High temperature soldering guaranted:260°C/10s
- ♦ Reel size: 7 inch
- ∻MSL 1

APPLICATIONS

- ♦ Cell Phone Handsets and Accessories
- Microprocessor based equipment
- ♦ Personal Digital Assistants (PDA's)
- \diamond Notebooks, Desktops, and Servers
- ♦ Portable Instrumentation
- ♦Networking and Telecom
- ♦ Serial and Parallel Ports.
- ♦ Peripherals

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PIN CONFIGURATION



PACKAGE OUTLINE







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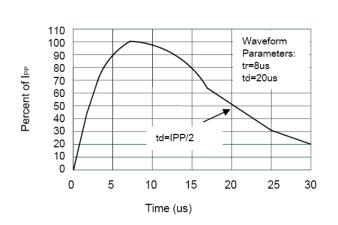
ABSOLUTE MAXIMUM RATING							
Symbol	Parameter	Value	Units				
\mathbf{V}_{ESD}	ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	±15 ±8	kV				
P _{PP}	Peak Pulse Power (8/20µs)	350	W				
T _{OPT}	Operating Temperature	-55/+150	°C				
T _{STG}	Storage Temperature	-55/+150	°C				
ΤL	Lead Soldering Temperature	260 (10 sec.)	°C				

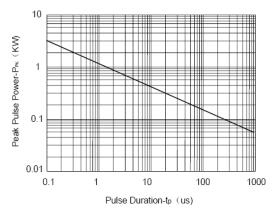
ELECTRICAL CHARACTERISTICS (Tamb=25°C)									
PART NUMBE R	DEVICE MARKING	V _{RWM} (V) (max.)	V _B (V) (min.)	I _T (mA)	V _C @1A (V) (max.)		/ _C V) (@A)	Ι _R (μΑ) (max.	C _T (pF) (max.)
SD03C	2A	3.3	4.0	1	7.5) 13.0	20	40	450
SD05C	2B	5.0	6.0	1	9.8	18.0	17	10	200
SD08C	2C	8.0	8.5	1	13.4	24.0	15	2	120
SD12C	12B	12.0	13.3	1	19.0	32.0	11	1	75
SD15C	2J	15.0	16.7	1	24.0	38.0	10	1	68
SD18C	2K	18.0	20.0	1	29.0	45.0	9	1	57
SD24C	2H	24.0	26.7	1	43.0	52.0	7	1	50
SD36C	2N	36.0	40.0	1	60.0	75.0	5	1	35

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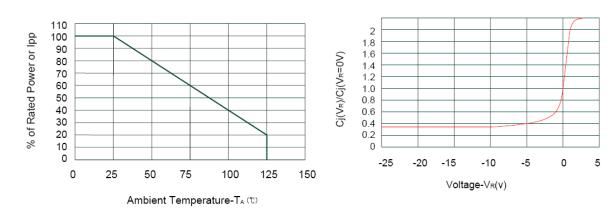
ELECTRICAL CHARACTERISTICS CURVE





Pulse Waveform

Non-Repetitive Peak Pulse Power vs. Pulse Time



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Power Derating Curve

Junction Capacitance vs. Reverse Voltage

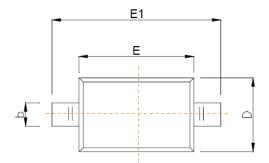
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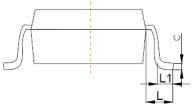


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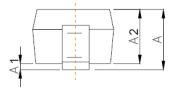
Bidirectional TVS Diodes

SOD-323 PACKAGE OUTLINE DIMENSIONS

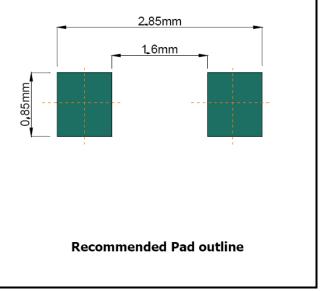




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Symbol	Dimensions In Millimeters					
Symbol	Min	Max				
А		1.00				
A1	0.000	0.100				
A2	0.800	0.900				
b	0.250	0.350 0.150 1.400				
с	0.080					
D	1.200					
E	1.600	1.800				
E1	2.500	2.700				
е	1.800	2.040				
L	0.475 REF					
L1	0.250	0.400				
θ	0°	8°				



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